7F, No. 349, Sec. 2, Renhe Road, Dashi, Taoyuan, Taiwan (R.O.C) 335

Cat No.: 7-1S-1000-044

Revision: 2

# AllnGaP LED DICE

# Part NO.: AOC-1120xA Series

#### **Features**

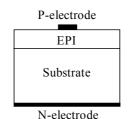
- Orange Color Emission
- Excellent performance and high efficiency
- Great reliability even in harsh environment

## **Description**

AOC-112OxA series is a orange color emitting AlInGaP LED grown by MOCVD technique. Its structure enables enhanced quantum efficiency and therefore a greater light intensity. This device is designed to suit the growing demand in the compact size electronic goods.

### **Chip Dimensions**





Chip Size: 10.8mil×10.8mil±0.5mil Bonding Pad: \phi4.0mil±0.4mil Chip Thickness: 6.5mil±1.0mil

### **Specification and Optical Characteristics**

Measuring Item	Symbol	Condition	Min	Тур	Max	Uni	it
Forward Voltage	$V_{\mathrm{F}}$	I <sub>F</sub> =20mA	1.70	-	2.20	V	
Reverse Current	Ir	V <sub>R</sub> =-5V	-	-	1.0	μΑ	4
Dominant Wavelength	λd	I <sub>F</sub> =20mA	600	-	620	nm	1
Max. Junction Temperature	$T_{\text{max}}$	-	≦ 115			°(	C
Max. DC forward current	$I_f$	Ta = 25°C	≤ 50			m	ıΑ
Max. pulse forward current	ī.	Ta = 25°C		≤ 100	<b>\</b>	m	mA
(Pulse width 0.1 msec, frequency=1 kHz.)	$I_{fm}$		⊒ 100			11.	IIIA
Storage temperature	$T_{\mathrm{stg}}$	Chip on tape	0 ~ 40				C
		Only chip	<b>-4</b> 0 ~ 80				

# Available Dominate Wavelength and Iv Matrix

Part No.	Wavelength	≥ 50	≥ 60	≥ 70	≥ 80	≥ 90	≥ 100	≥ 110	≥ 120	≥ 130
	Range	mcd	mcd	mcd	mcd	mcd	mcd	mcd	mcd	mcd
112 OSA	$600\sim610\;nm$	D	Е	F	G	Н	I	J	K	L
112 OLA	610 ~ 620 nm	D	Е	F	G	Н	I	J	-	-

#### Not:

- 1. All measurements are done with AOC's standard testing equipment.
- 2. Luminance intensity is measured on bare chip.
- 3. Above contents are subject to change without notice.
- Special requests are also welcome, please contact AOC's sale representative for any request.

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